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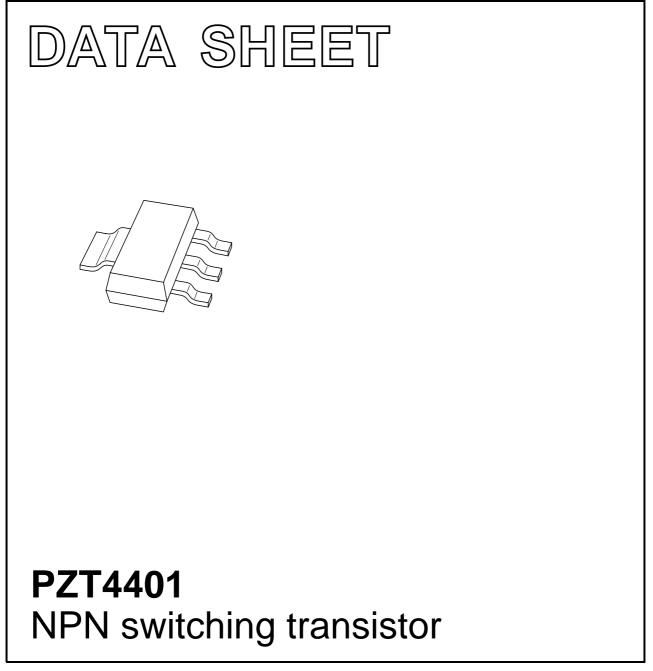
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Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS



Product data sheet

1999 May 10



NPN switching transistor

FEATURES

- High current (max. 600 mA)
- · Low voltage.

APPLICATIONS

 Switching and linear amplification in industrial and consumer applications.

DESCRIPTION

NPN switching transistor in a SOT223 plastic package. PNP complement: PZT4403.

PINNING

| PIN | DESCRIPTION |
|------|-------------|
| 1 | base |
| 2, 4 | collector |
| 3 | emitter |

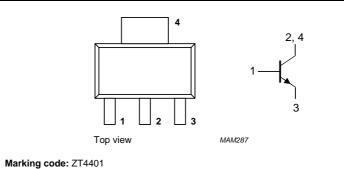


Fig.1 Simplified outline (SOT223) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|--------------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | 60 | V |
| V _{CEO} | collector-emitter voltage | open base | - | 40 | V |
| V _{EBO} | emitter-base voltage | open collector | - | 6 | V |
| I _C | collector current (DC) | | _ | 600 | mA |
| I _{CM} | peak collector current | | _ | 800 | mA |
| I _{BM} | peak base current | | - | 200 | mA |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C;$ note 1 | _ | 1150 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm². For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

PZT4401

NPN switching transistor

PZT4401

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 109 | K/W |
| R _{th j-s} | thermal resistance from junction to soldering point | | 28 | K/W |

Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm². For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$ unless otherwise specified.

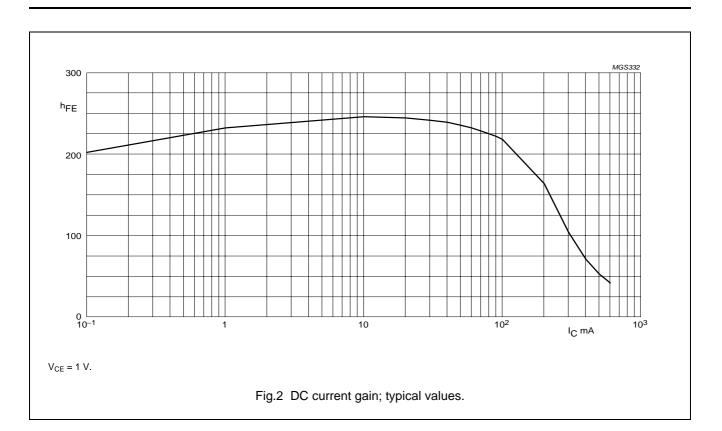
| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------------------|--------------------------------------|--|------|------|------|
| I _{CBO} | collector cut-off current | I _E = 0; V _{CB} = 60 V | _ | 50 | nA |
| I _{EBO} | emitter cut-off current | $I_{C} = 0; V_{EB} = 6 V$ | - | 50 | nA |
| h _{FE} | DC current gain | V _{CE} = 1 V; see Fig.2 | | | |
| | | I _C = 0.1 mA | 20 | - | |
| | | $I_{\rm C} = 1 {\rm mA}$ | 40 | _ | |
| | | I _C = 10 mA | 80 | _ | |
| | | IC = 150 mA; note 1 | 100 | 300 | |
| | | V _{CE} = 2 V; I _C = 500 mA; note 1 | 40 | - | |
| V _{CEsat} | collector-emitter saturation voltage | I _C = 150 mA; I _B = 15 mA; note 1 | - | 400 | mV |
| | | $I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}; \text{ note } 1$ | - | 750 | mV |
| V _{BEsat} | base-emitter saturation voltage | I _C = 150 mA; I _B = 15 mA; note 1 | - | 950 | mV |
| | | IC = 500 mA; IB = 50 mA; note 1 | - | 1200 | mV |
| C _c | collector capacitance | I _E = i _e = 0; V _{CB} = 5 V; f = 1 MHz | - | 8 | pF |
| C _e | emitter capacitance | $I_{C} = i_{c} = 0; V_{EB} = 500 \text{ mV}; f = 1 \text{ MHz}$ | - | 30 | pF |
| f _T | transition frequency | I _C = 20 mA; V _{CE} = 10 V; f = 100 MHz | 250 | - | MHz |
| Switching t | imes (between 10% and 90% lev | els); see Fig.3 | | | |
| t _{on} | turn-on time | I _{Con} = 150 mA; I _{Bon} = 15 mA; | _ | 35 | ns |
| t _d | delay time | $I_{Boff} = -15 \text{ mA}; V_{BB} = -3.5 \text{ V};$ $V_{CC} = 29.5 \text{ V}$ | _ | 15 | ns |
| t _r | rise time | | _ | 20 | ns |
| t _{off} | turn-off time | | - | 250 | ns |
| t _s | storage time |] | - | 200 | ns |
| t _f | fall time |] | - | 60 | ns |

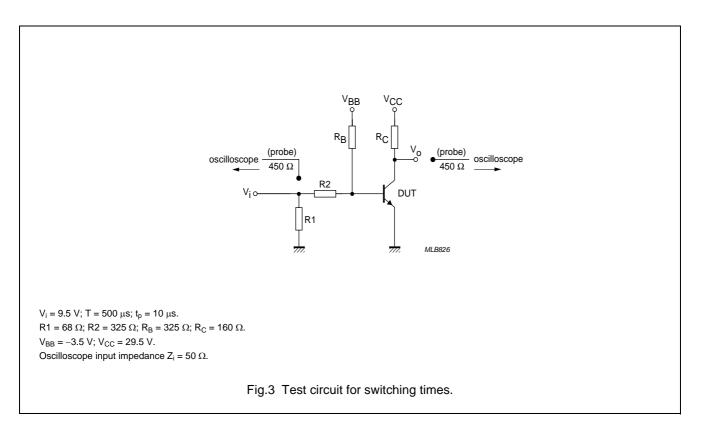
Note

1. Pulse test: $t_p \leq 300~\mu\text{s};~\delta \leq 0.02.$

PZT4401

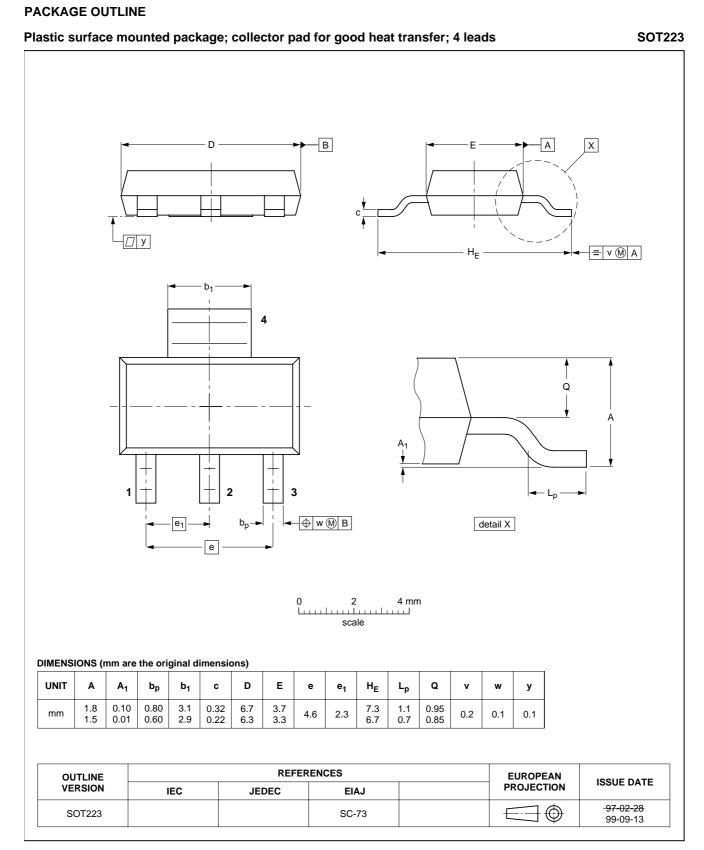
NPN switching transistor





PZT4401

NPN switching transistor



NPN switching transistor

PZT4401

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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